8-bit parallel-in/serial-out shift register Rev. 3 — 21 September 2021

### 1. General description

The 74LV165-Q100 is an 8-bit serial or parallel-in/serial-out shift register. The device features a serial data input (DS), eight parallel data inputs (D0 to D7) and two complementary serial outputs (Q7 and Q7). When the parallel load input (PL) is LOW the data from D0 to D7 is loaded into the shift register asynchronously. When PL is HIGH data enters the register serially at DS. When the clock enable input ( $\overline{CE}$ ) is LOW data is shifted on the LOW-to-HIGH transitions of the CP input. A HIGH on  $\overline{CE}$  will disable the CP input. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess V<sub>CC</sub>.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 1.0 to 5.5 V
- CMOS low power dissipation
- Direct interface with TTL levels (2.7 V to 3.6 V)
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Optimized for low voltage applications: 1.0 V to 3.6 V
- Synchronous parallel-to-serial applications
- Synchronous serial input for easy expansion
- Complies with JEDEC standards:
  - JESD8-7 (1.65 V to 1.95 V)
  - JESD8-5 (2.3 V to 2.7 V)
  - JESD8C (2.7 V to 3.6 V)
  - JESD36 (4.5 V to 5.5 V)
- ESD protection:
  - MIL-STD-833, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0  $\Omega$ )

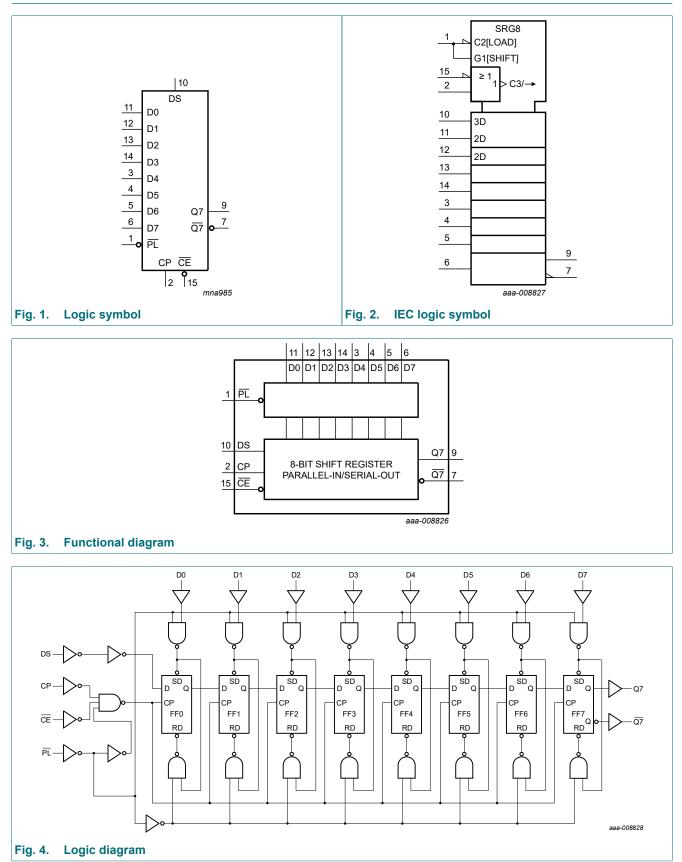
### 3. Ordering information

### Table 1. Ordering information

Type number Package				
	Temperature range	Name	Description	Version
74LV165D-Q100	-40 °C to +125 °C		plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74LV165PW-Q100	-40 °C to +125 °C		plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1

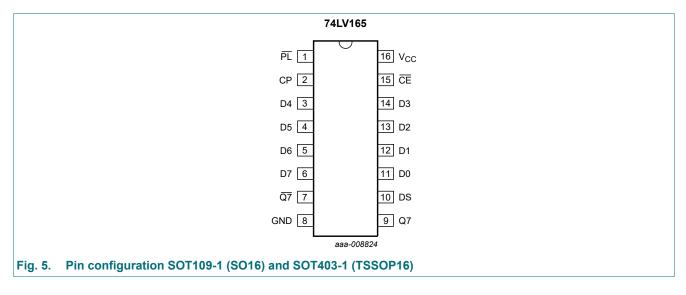
# ne<mark>x</mark>peria

### 4. Functional diagram



### 5. Pinning information





### 5.2. Pin description

Table 2. Pin description		
Symbol	Pin	Description
PL	1	parallel enable input (active LOW)
СР	2	clock input (LOW-to-HIGH edge-triggered)
Q7	7	complementary serial output from the last stage
GND	8	ground (0 V)
Q7	9	serial output from the last stage
DS	10	serial data input
D0, D1, D2, D3, D4, D5, D6, D7	11, 12, 13, 14, 3, 4, 5, 6	parallel data inputs
CE	15	clock enable input (active LOW)
V <sub>CC</sub>	16	positive supply voltage

### 6. Functional description

#### Table 3. Function table

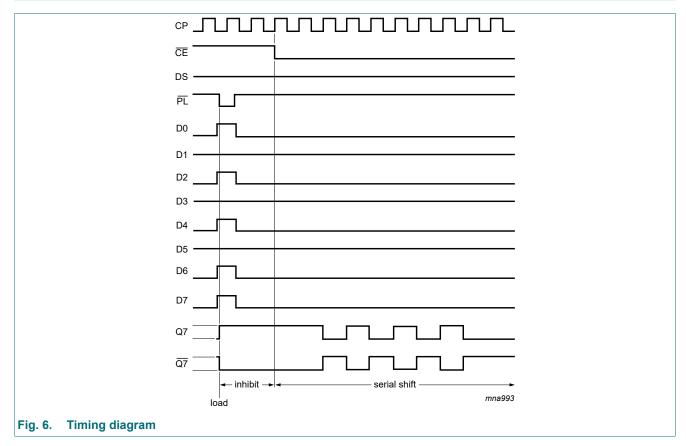
H = HIGH voltage level; h = HIGH voltage level one set-up time prior to the LOW-to-HIGH clock transition;

L = LOW voltage level; I = LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition;

*q* = state of the referenced output one set-up time prior to the LOW-to-HIGH clock transition;

 $X = don't care; \uparrow = LOW-to-HIGH clock transition.$ 

Operating modes	Input	S				Qn reg	isters	Outpu	t
	PL	CE	СР	DS	D0 to D7	Q0	Q1 to Q6	Q7	<b>Q7</b>
parallel load	L	Х	Х	Х	L	L	L to L	L	Н
	L	Х	Х	Х	Н	Н	H to H	Н	L
serial shift	Н	L	1	I	X	L	q0 to q5	q6	<u>q6</u>
	Н	L	1	h	Х	Н	q0 to q5	q6	<u>q6</u>
hold "do nothing"	Н	Н	Х	Х	Х	q0	q1 to q6	q7	q7



### 7. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V) [1]

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7	V
I <sub>IK</sub>	input clamping current	$V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	-	20	mA
VI	input voltage		-0.5	+7	V
I <sub>OK</sub>	output clamping current	$V_{\rm O}$ > $V_{\rm CC}$ or $V_{\rm O}$ < 0	-	±50	mA
I <sub>O</sub>	output current	$-0.5 V < V_O < V_{CC} + 0.5 V$	-	±25	mA
I <sub>CC</sub>	supply current		-	+50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C [2]	-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT109-1 (SO16) package: P<sub>tot</sub> derates linearly with 12.4 mW/K above 110 °C.

For SOT403-1 (TSSOP16) package: Ptot derates linearly with 8.5 mW/K above 91 °C.

### 8. Recommended operating conditions

#### Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CC</sub>	supply voltage		1.0	3.3	5.5	V
VI	input voltage		0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	-	+85	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 1.0 V to 2.0 V	0	-	500	ns/V
		V <sub>CC</sub> = 2.0 V to 2.7 V	0	-	200	ns/V
		V <sub>CC</sub> = 2.7 V to 3.6 V	0	-	100	ns/V
		V <sub>CC</sub> = 3.6 V to 5.5 V	0	-	50	ns/V

### 9. Static characteristics

#### Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol Parameter		Conditions	-4(	) °C to +8	5 °C	-40 °C to	o +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	-
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 1.2 V	0.9	-	-	0.9	-	V
	input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V	1.4	-	-	1.4	-	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	2.0	-	-	2.0	-	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	0.7V <sub>CC</sub>	-	-	0.7V <sub>CC</sub>	-	V
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 1.2 V	-	-	0.3	-	0.3	V
	input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.6	-	0.6	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	0.8	-	0.8	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.3V <sub>CC</sub>	-	0.3V <sub>CC</sub>	
V <sub>OH</sub>	HIGH-level	$V_{I} = V_{IH}$ or $V_{IL}$ ; $I_{O} = -100 \ \mu A$						
	output voltage	V <sub>CC</sub> = 1.2 V	-	1.2		_		
		V <sub>CC</sub> = 2.0 V	1.8	2.0	-	1.8	-	V
		V <sub>CC</sub> = 2.7 V	2.5	2.7	_	2.5	-	V
		V <sub>CC</sub> = 3.0 V	2.8	3.0	-	2.8	-	V
		V <sub>CC</sub> = 4.5 V	4.3	4.5	-	4.3	-	V
		standard outputs: $V_I = V_{IH}$ or $V_{IL}$						-
		V <sub>CC</sub> = 3.0 V; I <sub>O</sub> = -6 mA	2.40	2.82	_	2.20	-	V
		V <sub>CC</sub> = 4.5 V; I <sub>O</sub> = -12 mA	3.60	4.20	-	3.50	-	V
V <sub>OL</sub>	LOW-level	$V_{I} = V_{IH}$ or $V_{IL}$ ; $I_{O} = 100 \ \mu A$						
	output voltage	V <sub>CC</sub> = 1.2 V	-	0	_	_	-	
		V <sub>CC</sub> = 2.0 V	-	0	0.2	1.8	0.2	V
		V <sub>CC</sub> = 2.7 V	-	0	0.2	2.5	0.2	V
		V <sub>CC</sub> = 3.0 V	-	0	0.2	2.8	0.2	V
		V <sub>CC</sub> = 4.5 V	-	0	0.2	4.3	0.2	V
		standard outputs: V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>						
		V <sub>CC</sub> = 3.0 V; I <sub>O</sub> = 6 mA	-	0.25	0.40	_	0.50	V
		V <sub>CC</sub> = 4.5 V; I <sub>O</sub> = 12 mA	-	0.35	0.55	_	0.65	V
I	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±1	-	±1	μA
l <sub>cc</sub>	supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V	-	-	20	-	160	μA
ΔI <sub>CC</sub>	additional supply current	$V_{I} = V_{CC} - 0.6 V;$ $V_{CC} = 2.7 V \text{ to } 3.6 V$	-	-	500	-	850	μA
CI	input capacitance		-	3.5	-	-	-	pF

[1] Typical values are measured at  $T_{amb}$  = 25 °C.

### **10.** Dynamic characteristics

### Table 7. Dynamic characteristics

GND (ground = 0 V); for test circuit, see Fig. 12

Symbol	Parameter	Conditions	-4	0 °C to +85	5 °C	-40 °C to	o +125 °C	Unit
			Min	Typ[1]	Мах	Min	Max	
t <sub>pd</sub>	propagation delay	CE, CP to Q7, Q7;         [2]           see Fig. 7 and Fig. 8						
		V <sub>CC</sub> = 1.2 V	-	115	-	-	-	ns
		V <sub>CC</sub> = 2.0 V	-	38	61	-	76	ns
		V <sub>CC</sub> = 2.7 V	-	27	43	-	54	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V [3]	-	22	36	-	45	ns
		V <sub>CC</sub> = 3.3 V; C <sub>L</sub> = 15 pF	-	18	-	-	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V [4]	-	15	24	-	30	ns
		PL to Q7, Q7; see Fig. 8						
		V <sub>CC</sub> = 1.2 V	-	110	-	-	-	ns
		V <sub>CC</sub> = 2.0 V	-	35	56	-	70	ns
		V <sub>CC</sub> = 2.7 V	-	24	39	-	49	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V [3]	-	20	33	-	41	ns
		V <sub>CC</sub> = 3.3 V; C <sub>L</sub> = 15 pF	-	18	-	-	-	ns
		$V_{\rm CC}$ = 4.5 V to 5.5 V [4]	-	14	22	-	27	ns
		D7 to Q7, Q7; see Fig. 9						
		V <sub>CC</sub> = 1.2 V	-	90	-	-	-	ns
		V <sub>CC</sub> = 2.0 V	-	28	45	-	56	ns
		V <sub>CC</sub> = 2.7 V	-	20	32	-	40	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V [3]	-	17	27	-	33	ns
		V <sub>CC</sub> = 3.3 V; C <sub>L</sub> = 15 pF	-	14	-	-	-	ns
		$V_{\rm CC}$ = 4.5 V to 5.5 V [4]	-	11	18	-	22	ns
t <sub>W</sub>	pulse width	CP input HIGH to LOW; see Fig. 7						
		V <sub>CC</sub> = 2.0 V	34	10	-	41	-	ns
		V <sub>CC</sub> = 2.7 V	25	8	-	30	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V [3]	20	7	-	24	-	ns
		$V_{\rm CC}$ = 4.5 V to 5.5 V [4]	15	5	-	18	-	ns
		PL input LOW; see Fig. 8						
		V <sub>CC</sub> = 2.0 V	34	10	-	41	-	ns
		V <sub>CC</sub> = 2.7 V	25	8	-	30	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V [3]	20	7	-	24	-	ns
		$V_{\rm CC}$ = 4.5 V to 5.5 V [4]	15	5	-	18	-	ns
t <sub>rec</sub>	recovery time	PL to CP, CE; see Fig. 8						
		V <sub>CC</sub> = 1.2 V	-	40	-	-	-	ns
		V <sub>CC</sub> = 2.0 V	24	15	-	30	-	ns
		V <sub>CC</sub> = 2.7 V	18	11	-	23	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V [3]	17	10	-	21	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V [4]	12	7	-	15	-	ns

### 8-bit parallel-in/serial-out shift register

Symbol	Parameter	Conditions		-4(	) °C to +85	°C	-40 °C to	o +125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
t <sub>su</sub>	set-up time	DS to CP, CE; see Fig. 10							
		V <sub>CC</sub> = 1.2 V		-	-8	-	-	-	ns
		V <sub>CC</sub> = 2.0 V		22	-2	-	26	-	ns
		V <sub>CC</sub> = 2.7 V		16	-1	-	19	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	13	-1	-	15	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	[4]	9	0	-	10	-	ns
		$\overline{CE}$ to CP, CP to $\overline{CE}$ ; see Fig. 10							
		V <sub>CC</sub> = 1.2 V		-	20	-	-	-	ns
		V <sub>CC</sub> = 2.0 V		22	7	-	26	-	ns
		V <sub>CC</sub> = 2.7 V		16	5	-	19	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	13	4	-	15	-	ns
		$V_{CC}$ = 4.5 V to 5.5 V	[4]	9	3	-	10	-	ns
		Dn to PL; see Fig. 11							
		V <sub>CC</sub> = 1.2 V		-	25	-	-	-	ns
		V <sub>CC</sub> = 2.0 V		22	8	-	26	-	ns
		V <sub>CC</sub> = 2.7 V		16	6	-	19	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	13	5	-	15	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	[4]	9	4	-	10	-	ns
t <sub>h</sub>	hold time	DS to CP, CE; Dn to PL; see <u>Fig. 10</u> and <u>Fig. 11</u>							
		V <sub>CC</sub> = 1.2 V		-	20	-	-	-	ns
		V <sub>CC</sub> = 2.0 V		22	7	-	26	-	ns
		V <sub>CC</sub> = 2.7 V		16	5	-	19	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	13	4	-	15	-	ns
		$V_{CC}$ = 4.5 V to 5.5 V	[4]	9	3	-	10	-	ns
		$\overline{CE}$ to CP, CP to $\overline{CE}$ ; see <u>Fig. 10</u>							
		V <sub>CC</sub> = 1.2 V		-	-30	-	-	-	ns
		V <sub>CC</sub> = 2.0 V		5	-8	-	5	-	ns
		V <sub>CC</sub> = 2.7 V		5	-6	-	5	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	5	-5	-	5	-	ns
		$V_{CC}$ = 4.5 V to 5.5 V	[4]	5	-4	-	5	-	ns
f <sub>max</sub>	maximum	see <u>Fig. 7</u>							
	frequency	V <sub>CC</sub> = 2.0 V		14	40	-	12	-	MHz
		V <sub>CC</sub> = 2.7 V		19	60	-	16	-	MHz
		V <sub>CC</sub> = 3.0 V to 3.6 V	[3]	24	65	-	20	-	MHz
		V <sub>CC</sub> = 3.3 V; C <sub>L</sub> = 15 pF		-	78	-	-	-	MHz
		V <sub>CC</sub> = 4.5 V to 5.5 V	[4]	36	75	-	30	-	MHz

#### 8-bit parallel-in/serial-out shift register

Symbol	Parameter	Conditions	-40	°C to +85	°C	-40 °C to	+125 °C	Unit
			Min	Typ <mark>[1]</mark>	Max	Min	Мах	
C <sub>PD</sub>	power dissipation capacitance	$V_{I} = GND \text{ to } V_{CC}; $ [5] $V_{CC} = 3.3 \text{ V} $	-	35	-	-	-	pF

[1] Typical values are measured at  $T_{amb}$  = 25 °C.

[2]  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .

[3] Typical values are measured at  $V_{CC}$  = 3.3 V.

[4] Typical values are measured at  $V_{CC}$  = 5.0 V.

[5]  $C_{PD}$  is used to determine the dynamic power dissipation  $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o) (P_D \text{ in } \mu W)$ , where:  $f_i = \text{input frequency in MHz}$ ;

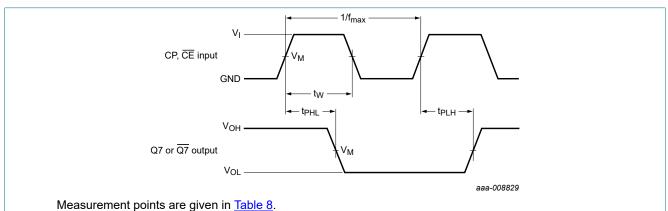
 $f_o$  = output frequency in MHz;

 $\Sigma$  (C<sub>L</sub> x V<sub>CC</sub><sup>2</sup> x f<sub>o</sub>) = sum of outputs;

 $C_L$  = output load capacitance in pF;

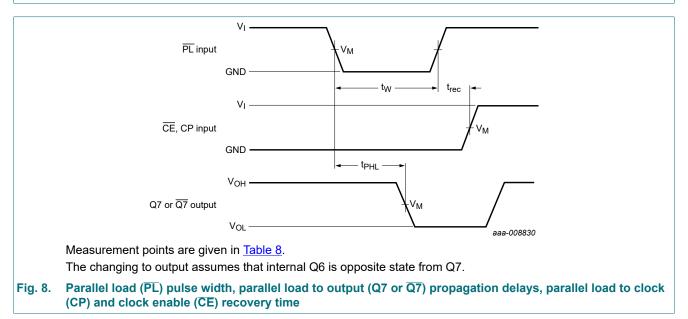
 $V_{CC}$  = supply voltage in V.

### 10.1. Waveforms and test circuit

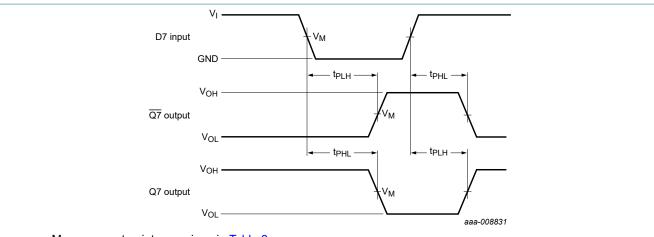


The changing to output assumes that internal Q6 is opposite state from Q7.

Fig. 7. Clock pulse (CP) and clock enable (CE) to output (Q7 or Q7) propagation delays, clock pulse width and maximum clock frequency



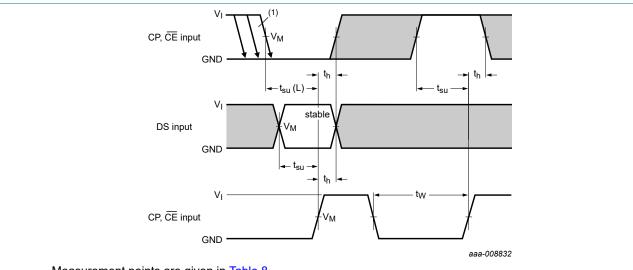
### 8-bit parallel-in/serial-out shift register



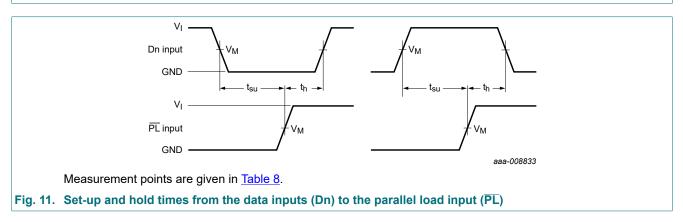
Measurement points are given in <u>Table 8</u>.

The changing to output assumes that internal Q6 is opposite state from Q7.

#### Fig. 9. Data input (Dn) to output (Q7 or $\overline{Q7}$ ) propagation delays when $\overline{PL}$ is LOW



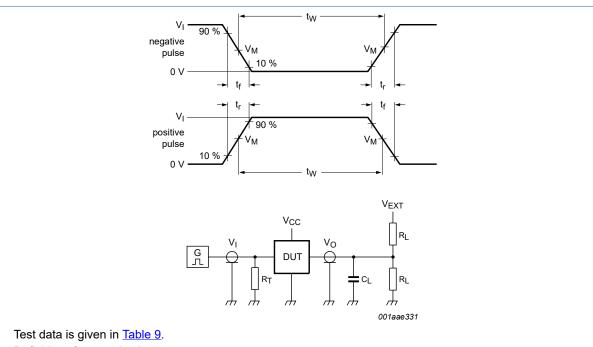
- Measurement points are given in <u>Table 8</u>.
- (1) CE may change only from HIGH-to-LOW while CP is LOW. The shaded areas indicate when the input is permitted to change for predictable output performance.
- Fig. 10. Set-up and hold times



### 8-bit parallel-in/serial-out shift register

### Table 8. Measurement points

Supply voltage	Input	Output
V <sub>cc</sub>	V <sub>M</sub>	V <sub>M</sub>
< 2.7 V	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>
2.7 V to 3.6 V	1.5 V	1.5 V
≥ 4.5 V	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>



Definitions for test circuit:

R<sub>L</sub> = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_{T}$  = Termination resistance should be equal to output impedance  $Z_{o}$  of the pulse generator.

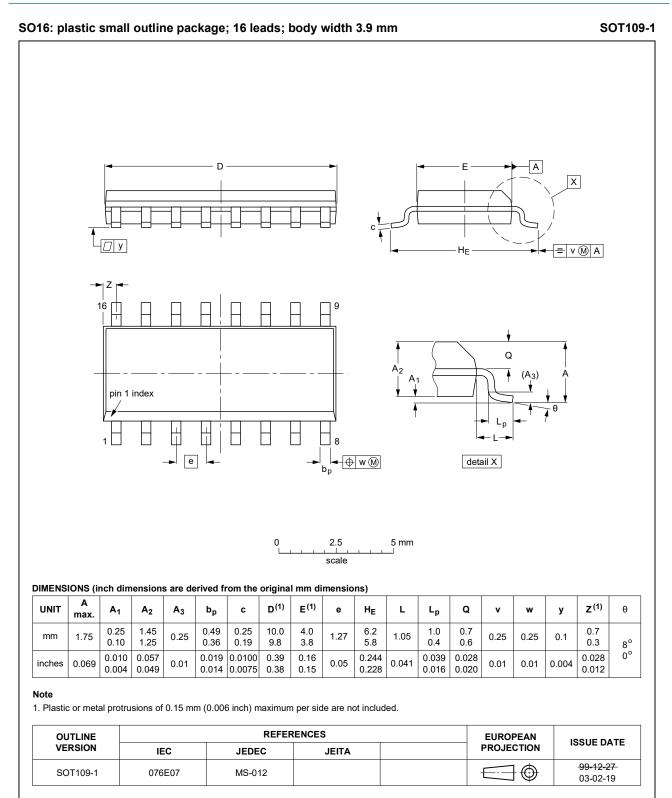
V<sub>EXT</sub> = External voltage for measuring switching times.

#### Fig. 12. Test circuit for measuring switching times

### Table 9. Test data

Supply voltage	Input	put I		₋oad		
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	RL	t <sub>PHL</sub> , t <sub>PLH</sub>	
< 2.7 V	V <sub>CC</sub>	2.5 ns	50 pF	1 kΩ	open	
2.7 V to 3.6 V	2.7 V	2.5 ns	50 pF, 15 pF	1 kΩ	open	
≥ 4.5 V	V <sub>CC</sub>	2.5 ns	50 pF	1 kΩ	open	

### **11. Package outline**



#### Fig. 13. Package outline SOT109-1 (SO16)

74LV165\_Q100

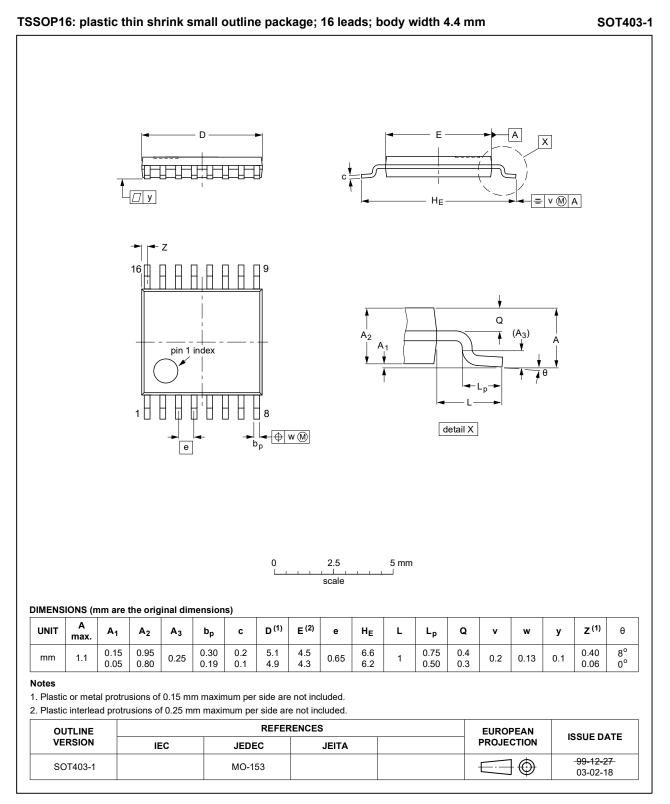


Fig. 14. Package outline SOT403-1 (TSSOP16)

### **12. Abbreviations**

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MIL	Military
MM	Machine Model
TTL	Transistor-Transistor Logic

### 13. Revision history

### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LV165_Q100 v.3	20210921	Product data sheet	-	74LV165_Q100 v.2
Modifications:	Nexperia. <ul> <li>Legal texts hat</li> <li><u>Section 1</u> and</li> </ul>	this data sheet has been redes ve been adapted to the new co <u>Section 2</u> updated. ating values for P <sub>tot</sub> total powe	ompany name where	appropriate.
74LV165_Q100 v.2	20140224	Product data sheet	-	74LV165_Q100 v.1
Modifications:	Typo corrected	in <u>Table 2</u>		
74LV165_Q100 v.1	20131111	Product data sheet	-	-

### 14. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

#### **Definitions**

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

**Product specification** — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

#### **Disclaimers**

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of Nexperia.

**Right to make changes** — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use in automotive applications — This Nexperia product has been qualified for use in automotive applications. Unless otherwise agreed in writing, the product is not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or

#### 8-bit parallel-in/serial-out shift register

equipment, nor in applications where failure or malfunction of an Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Quick reference data** — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at <u>http://www.nexperia.com/profile/terms</u>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

**Translations** — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

#### Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

### Contents

1. General description	1
2. Features and benefits	1
3. Ordering information	1
4. Functional diagram	2
5. Pinning information	3
5.1. Pinning	3
5.2. Pin description	3
6. Functional description	4
7. Limiting values	5
8. Recommended operating conditions	5
9. Static characteristics	6
10. Dynamic characteristics	7
10.1. Waveforms and test circuit	9
11. Package outline	12
12. Abbreviations	14
13. Revision history	14
14. Legal information	15

#### © Nexperia B.V. 2021. All rights reserved

For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 21 September 2021

74LV165\_Q100